

Notice of References Cited

Application/Control No

10/064,869

Applicant(s)/Patent Under

Reexamination

BROWN ET AL

Examiner

Howard Weiss

Art Unit

2814

Page 1 of 1

U.S. PATENT DOCUMENTS

| * | | Document Number Country Code-Number-Kind Code | Date MM-YYYY | Name | Classification |
|---|---|--|-----------------|--------------|----------------|
| | A | US-6 198 151 | 03-2001 | Wada | 257/520 |
| | B | US-5 943,279 | 08-1999 | Wada | 365/205 |
| | C | US-5,329,479 | 07-1994 | Ota et al | 365/149 |
| | D | US-5,241,211 | 08-1993 | Tashiro | 257/506 |
| | E | US-4,888,733 | 12-1989 | Mobley | 365/145 |
| | F | US-4,641,165 | 02-1987 | Iizuka et al | 257/311 |
| | G | US- | | | |
| | H | US- | | | |
| | I | US- | | | |
| | J | US- | | | |
| | K | US- | | | |
| | L | US- | | | |
| | M | US- | | | |

FOREIGN PATENT DOCUMENTS

| * | | Document Number Country Code-Number-Kind Code | Date MM-YYYY | Country | Name | Classification |
|---|---|--|-----------------|---------|------|----------------|
| | N | | | | | |
| | O | | | | | |
| | P | | | | | |
| | Q | | | | | |
| | R | | | | | |
| | S | | | | | |
| | T | | | | | |

NON-PATENT DOCUMENTS

| * | | Include as applicable: Author, Title, Date, Publisher, Edition or Volume, Pertinent Pages) |
|---|---|--|
| | U | Choi, Y.-K. et al., "30 nm ultra-thin-body SOI MOSFET with selective deposited Ge raised S/D", June 2000, 58th Dev. Res. Conf. (DRC), pp. 23-4 |
| | V | |
| | W | |
| | X | |

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a)).
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.